

SLD1135VS

650nm Index-Guided Red Laser Diode

Description

The SLD1135VS is a index-guided red laser diode for Laser pointer. The wavelength is 20nm shorter than SLD1122VS.

Features

- Small astigmatism (7µm typ.)
- Small package (\phi5.6mm)
- Single longitudinal mode
- Low operating voltage (2.4V Max)
- Max operating temperature = 40°C (Case temperature)

Applications

Laser pointer

Structure

- AlGaInP MQW laser diode
- PIN photodiode to monitor laser beam output

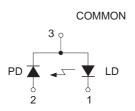
Recommend Optical Power Output

5mW

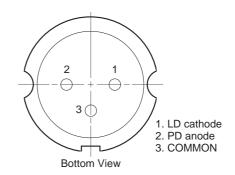
Absolute Maximum Ratings (Tc = 25°C)

 Optical power output 	Po		5	mW
 Reverse voltage 	Vr	LD	2	V
		PD	15	V
 Operating temperature 	Topr		-10 to +40	°C
 Storage temperature 	Tstg		-40 to +85	°C

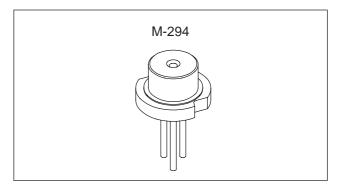
Connection Diagram



Pin Configuration



Sony reserves the right to change products and specifications without prior notice. This information does not convey any license by any implication or otherwise under any patents or other right. Application circuits shown, if any, are typical examples illustrating the operation of the devices. Sony cannot assume responsibility for any problems arising out of the use of these circuits.



It	em	Symbol	Conditions	Min.	Тур.	Max.	Unit
Threshold cur	rent	lth			30	40	mA
Operating cur	rent	Іор	Po = 5mW		35	45	mA
Operating vol	tage	Vop	Po = 5mW		2.2	2.4	V
Wavelength		λρ	Po = 5mW		650	660	nm
Radiation	Perpendicular	θ⊥		22	30	40	degree
angle	Parallel	θ//	Po = 5mW	5	7	12	degree
	Position	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW			±150	μm
Positional accuracy Ang	Angle	Δφ//				±3	degree
	Aligie	$\Delta \phi \perp$				±3	degree
Differential eff	ficiency	ηD	Po = 5mW	0.3	0.6	0.9	mW/mA
Astigmatism		As	Po = 5mW		7	15	μm
Monitor curre	nt	Imon	Po = 5mW, Vr = 5V	0.05	0.1	0.25	mA

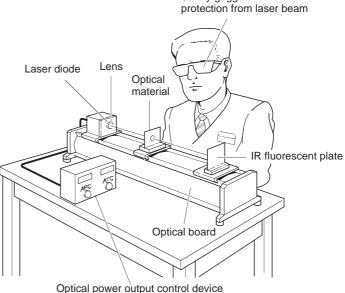
Electrical and Optical Characteristics (Tc = 25°C)

Tc: Case temperature

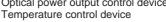
Handling Precautions

(1) Eye protection against laser beams

The optical output of laser diodes ranges from several mW to 4W. However the optical power density of the laser beam at the diode chip reaches 1MW/cm². Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.



Safety goggles for

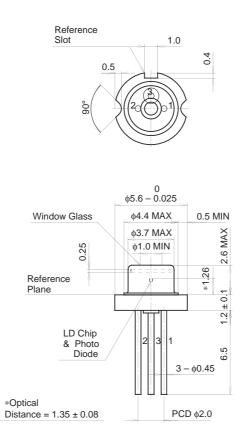


(2) Prevention of surge current and electrostatic discharge

Laser diode is most sensitive to electrostatic discharge among semiconductors. When a large current is passed through the laser diode even for an extremely short time (in the order of nanosecond), the strong light emitted from the laser diode promotes deterioration and then laser diodes are destroyed. Therefore, note that the surge current should not flow the laser diode driving circuit from switches and others. Also, if the laser diode is handled carelessly, it may be destructed instantly because electrostatic discharge is easily applied by a human body. Be great careful about excess current and electrostatic discharge.

Package Outline

Unit: mm



SONY CODE	M-294	PACKAGE WEIGHT	0.3g
EIAJ CODE			
JEDEC CODE			